

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China









4 OUTPUT PCIE GEN1/2/3 SYNTHESIZER

IDT5V41236

Recommended Applications

Four output synthesizer for PCIe Gen1/2/3

General Description

The IDT5V41236 is a PCIe Gen2/3 compliant spread-spectrum-capable clock generator. The device has 4 differential HCSL outputs and can be used in communication or embedded systems to substantially reduce electro-magnetic interference (EMI). The spread amount and output frequency are selectable via select pins.

Output Features

• 4 - 0.7V current mode differential HCSL output pairs

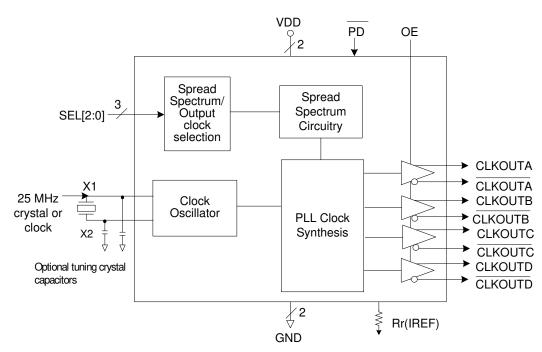
Features/Benefits

- 20-pin TSSOP/VFQFPN packages; small board footprint
- Spread-spectrum capable; reduces EMI
- Outputs can be terminated to LVDS; can drive a wider variety of devices
- · Power down pin; greater system power management
- OE control pin; greater system power management
- Spread% and frequency pin selection; no software required to configure device
- Industrial temperature range available; supports demanding embedded applications

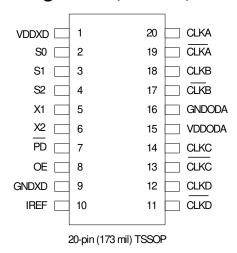
Key Specifications

- Cycle-to-cycle jitter < 100 ps
- Output-to-output skew < 50 ps
- PCle Gen2 phase jitter < 3.0ps RMS
- PCIe Gen3 phase jitter < 1.0ps RMS

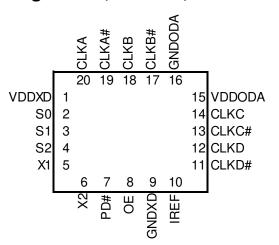
Block Diagram



Pin Assignment (20TSSOP)



Pin Assignment (20VFQFPN)



Spread Spectrum Selection Table

S2	S1	S0	Spread%	Spread Type	Output Frequency
0	0	0	-0.5	Down	100
0	0	1	-1.0	Down	100
0	1	0	-1.5	Down	100
0	1	1	No Spread	Not Applicable	100
1	0	0	-0.5	Down	200
1	0	1	-1.0	Down	200
1	1	0	-1.5	Down	200
1	1	1	No Spread	Not Applicable	200

Pin Descriptions

Pin	Pin	Pin	Pin Description
	Name	Туре	
1	VDDXD	Power	Connect to +3.3V digital supply.
2	S0	Input	Spread spectrum select pin #0. See table above. Internal pull-up resistor.
3	S1	Input	Spread spectrum select pin #1. See table above Internal pull-up resistor.
4	S2	Input	Spread spectrum select pin #2. See table above. Internal pull-up resistor.
5	X1	Input	Crystal connection. Connect to a fundamental mode crystal or clock input.
6	X2	Output	Crystal connection. Connect to a fundamental mode crystal or leave open.
7	PD#	Input	Powers down all PLLs and tri-states outputs when low. Internal pull-up resistor.
8	OE	Input	Provides output on, tri-states output (High = enable outputs; Low = disable outputs).
			Internal pull-up resistor.
9	GND	Power	Connect to digital ground.
10	IREF	Output	Precision resistor attached to this pin is connected to the internal current reference.
11	CLKD#	Output	Selectable 100/200MHz spread spectrum differential complement output clock D.
12	CLKD	Output	Selectable 100/200MHz spread spectrum differential true output clock D.
13	CLKC#	Output	Selectable 100/200MHz spread spectrum differential complement output clock C.
14	CLKC	Output	Selectable 100/200MHz spread spectrum differential true output clock C.
15	VDDODA	Power	Connect to +3.3V analog supply.
16	GND	Power	Connect to analog ground.
17	CLKB#	Output	Selectable 100/200MHz spread spectrum differential complement output clock B.
18	CLKB	Output	Selectable 100/200MHz spread spectrum differential true output clock B.
19	CLKA#	Output	Selectable 100/200MHz spread spectrum differential complement output clock A.
20	CLKA	Output	Selectable 100/200MHz spread spectrum differential true output clock A.

Application Information

Decoupling Capacitors

As with any high-performance mixed-signal IC, the IDT5V41236 must be isolated from system power supply noise to perform optimally.

Decoupling capacitors of 0.01µF must be connected between each VDD and the PCB ground plane.

PCB Layout Recommendations

For optimum device performance and lowest output phase noise, the following guidelines should be observed.

Each 0.01µF decoupling capacitor should be mounted on the component side of the board as close to the VDD pin as possible. No vias should be used between decoupling capacitor and VDD pin. The PCB trace to VDD pin should be kept as short as possible, as should the PCB trace to the ground via. Distance of the ferrite bead and bulk decoupling from the device is less critical.

2) An optimum layout is one with all components on the same side of the board, minimizing vias through other signal layers (the ferrite bead and bulk decoupling capacitor can be mounted on the back). Other signal traces should be routed away from the IDT5V41236.

This includes signal traces just underneath the device, or on layers adjacent to the ground plane layer used by the device.

External Components

A minimum number of external components are required for proper operation. Decoupling capacitors of 0.01 μ F should be connected between VDD and GND pairs (1,9 and 15,16) as close to the device as possible.

On chip capacitors- Crystal capacitors should be connected from pins X1 to ground and X2 to ground to optimize the initial accuracy. The value (in pf) of these crystal caps equal $(C_L-12)^*2$ in this equation, C_L =crystal load capacitance in pf. For example, for a crystal with a 16 pF load cap, each external crystal cap would be 8 pF. [(16-12)x2]=8.

Current Reference Source R_r (Iref)

If board target trace impedance (Z) is 50Ω , then Rr = 475Ω (1%), providing IREF of 2.32 mA, output current (I_{OH}) is equal to 6*IREF.

Load Resistors R_L

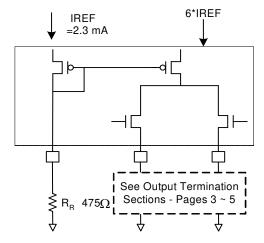
Since the clock outputs are open source outputs, 50 ohm external resistors to ground are to be connected at each clock output.

Output Termination

The PCI-Express differential clock outputs of the IDT5V41236 are open source drivers and require an external series resistor and a resistor to ground. These resistor values and their allowable locations are shown in detail in the **PCI-Express Layout Guidelines** section.

The IDT5V41236 can also be configured for LVDS compatible voltage levels. See the **LVDS Compatible Layout Guidelines** section.

Output Structures



General PCB Layout Recommendations

For optimum device performance and lowest output phase noise, the following guidelines should be observed.

- 1. Each $0.01\mu F$ decoupling capacitor should be mounted on the component side of the board as close to the VDD pin as possible.
- 2. No vias should be used between decoupling capacitor and VDD pin.
- 3. The PCB trace to VDD pin should be kept as short as possible, as should the PCB trace to the ground via. Distance of the ferrite bead and bulk decoupling from the device is less critical.
- 4. An optimum layout is one with all components on the same side of the board, minimizing vias through other signal layers (any ferrite beads and bulk decoupling capacitors can be mounted on the back). Other signal traces should be routed away from the IDT5V41236. This includes signal traces just underneath the device, or on layers adjacent to the ground plane layer used by the device.

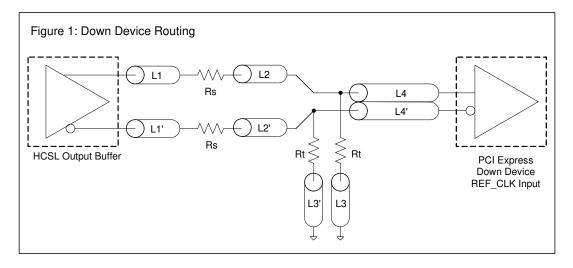
5

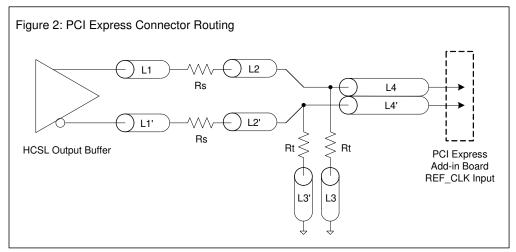
Layout Guidelines

SRC Reference Clock					
Common Recommendations for Differential Routing	Dimension or Value	Unit	Figure		
L1 length, route as non-coupled 50ohm trace	0.5 max	inch	1		
L2 length, route as non-coupled 50ohm trace	0.2 max	inch	1		
L3 length, route as non-coupled 50ohm trace	0.2 max	inch	1		
Rs	33	ohm	1		
Rt	49.9	ohm	1		

Down Device Differential Routing			
L4 length, route as coupled microstrip 100ohm differential trace	2 min to 16 max	inch	1
L4 length, route as coupled stripline 1000hm differential trace	1.8 min to 14.4 max	inch	1

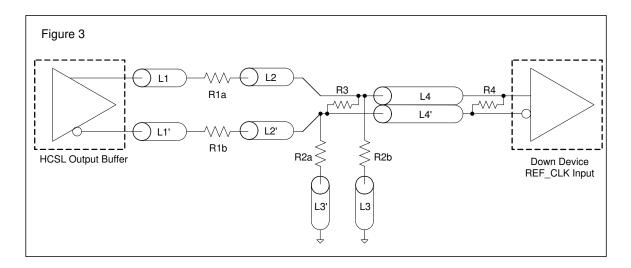
Differential Routing to PCI Express Connector			
L4 length, route as coupled microstrip 100ohm differential trace	0.25 to 14 max	inch	2
L4 length, route as coupled stripline 100ohm differential trace	0.225 min to 12.6 max	inch	2



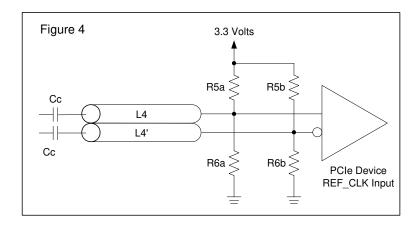


	Alternative Termination for LVDS and other Common Differential Signals (figure 3)									
VdiffVp-pVcmR1R2R3R4Note							Note			
0.45v	0.22v	1.08	33	150	100	100				
0.58	0.28	0.6	33	78.7	137	100				
0.80	0.40	0.6	33	78.7	none	100	ICS874003i-02 input compatible			
0.60	0.3	1.2	33	174	140	100	Standard LVDS			

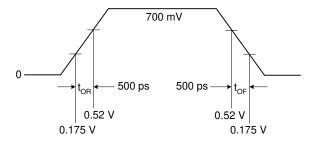
R1a = R1b = R1R2a = R2b = R2



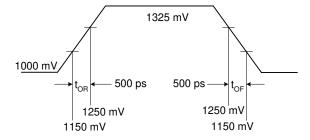
Cable Connected AC Coupled Application (figure 4)						
Component	Value	Note				
R5a, R5b	8.2K 5%					
R6a, R6b	1K 5%					
Сс	0.1 μF					
Vcm	0.350 volts					



Typical PCI-Express (HCSL) Waveform



Typical LVDS Waveform



Absolute Maximum Ratings

Stresses above the ratings listed below can cause permanent damage to the IDT5V41236. These ratings are stress ratings only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods can affect product reliability. Electrical parameters are guaranteed only over the recommended operating temperature range.

Item	Rating
Supply Voltage, VDD, VDDA	5.5V
All Inputs and Outputs	-0.5V to VDD+0.5V
Ambient Operating Temperature (commercial)	0 to +70°C
Ambient Operating Temperature (industrial)	-40 to +85°C
Storage Temperature	-65 to +150°C
Junction Temperature	125°C
Soldering Temperature	260°C
ESD Protection (Input)	2000V min. (HBM)

DC Electrical Characteristics

Unless stated otherwise, VDD = 3.3V ±5%, Ambient Temperature -40 to +85°C

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Supply Voltage	V		3.135	3.3	3.465	
Input High Voltage ¹	V _{IH}	S0, S1, S2, OE, X1, PD#	2.2		VDD +0.3	V
Input Low Voltage ¹	V_{IL}	S0, S1, S2, OE, X1, PD#	VSS-0.3		0.8	V
Input Leakage Current ²	I _{IL}	0 < Vin < VDD	-5		5	μΑ
Operating Supply Current	I _{DD}	$R_S=33\Omega$, $R_P=50\Omega$, $C_L=2$ pF		113	125	mA
@100 MHz	I _{DDOE}	OE =Low		42	50	mA
Input Capacitance	C _{IN}	Input pin capacitance			7	pF
Output Capacitance	C _{OUT}	Output pin capacitance			6	pF
X1, X2 Capacitance	C _{INX}				5	pF
Pin Inductance	L _{PIN}				5	nΗ
Output Impedance	Zo	CLK outputs	3.0			kΩ
Pull-up Resistance	R _{PUP}	S0, S1, OE, S2, PD#		100		kΩ

- 1. Single edge is monotonic when transitioning through region.
- 2. Inputs with pull-ups/-downs are not included.

AC Electrical Characteristics - CLKOUT (A:D)

Unless stated otherwise, VDD=3.3V ±5%, Ambient Temperature -40 to +85°C

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Input Frequency				25		MHz
Output Frequency		HCSL termination	25		200	MHz
Output Max. Voltage ^{1,2}	V_{MAX}		660	863	1150	mV
Output Min. Voltage ^{1,2}	V_{MIN}		-300	-53		mV
Crossing Point Voltage ^{1,2}		Absolute	250	377	550	mV
Crossing Point Voltage ^{1,2,4}		Variation over all edges		45	140	mV
Jitter, Cycle-to-Cycle ^{1,3}				29	125	ps
Modulation Frequency		Spread spectrum	30	32.9	33	kHz
Rise Time ^{1,2}	t _{OR}	From 0.175V to 0.525V	175	237	700	ps
Fall Time ^{1,2}	t _{OF}	From 0.525V to 0.175V	175	286	700	ps
Rise/Fall Time Variation ^{1,2}				73	125	ps
Skew between Outputs				8	50	ps
Duty Cycle ^{1,3}			45	52	55	%
Output Enable Time ⁵		All outputs			100	ns
Output Disable Time ⁵		All outputs			100	ns
Stabilization Time	t _{STABLE}	From power-up VDD=3.3V		1	1.8	ms
Spread Change Time	t _{SPREAD}	Settling period after spread change			30	ms

 $^{^{1}}$ Test setup is R_S=33 Ω , R_P=50 Ω with C_L=2 pF, Rr = 475 Ω (1%).

Electrical Characteristics - Differential Phase Jitter

T_A = Commercial and Industrial, Supply Voltage VDD = 3.3 V +/-5% SPEC **PARAMETER** Symbol Conditions Min Тур Units Notes Max PCIe Gen 1 30 1,2,3 86 ps (p-p) t_{iphaseG1} PCle Gen 2 ps 1 3 1,2,3 t_{iphaseG2Lo} 10kHz < f < 1.5MHz (RMS) Jitter, Phase PCle Gen 2 ps 3.1 2.3 1,2,3 t_{iphaseG2High} 1.5MHz < f < Nyquist (50MHz)(RMS) ps 1 PCIe Gen 3 0.7 1,2,3 t_{iphaseG3} (RMS)

² Measurement taken from a single-ended waveform.

³ Measurement taken from a differential waveform.

⁴ Measured at the crossing point where instantaneous voltages of both CLKOUT and CLKOUT are equal.

 $^{^{5}}$ CLKOUT pins are tri-stated when OE is asserted low. CLKOUT is driven differential when OE is high unless its \overline{PD} = low.

¹Guaranteed by design and characterization, not 100% tested in production.

²See http://www.pcisig.com for complete specs

³Applies to 100MHz, spread off and 0.5% down spread only.

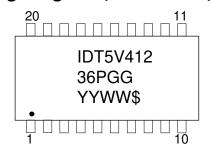
Thermal Characteristics (20TSSOP)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Thermal Resistance Junction to	$\theta_{\sf JA}$	Still air		93		°C/W
Ambient	θ_{JA}	1 m/s air flow		78		°C/W
	$\theta_{\sf JA}$	3 m/s air flow		65		°C/W
Thermal Resistance Junction to Case	$\theta_{\sf JC}$			20		°C/W

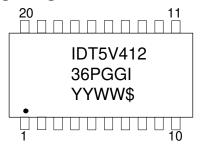
Thermal Characteristics (20VFQFPN)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Thermal Resistance Junction to	$\theta_{\sf JA}$	Still air		78		°C/W
Ambient	$\theta_{\sf JA}$	1 m/s air flow		70		°C/W
	$\theta_{\sf JA}$	3 m/s air flow		68		°C/W
Thermal Resistance Junction to Case	θЈС			37		°C/W

Marking Diagram (5V41236PGG)



Marking Diagram (5V41236PGGI)



Marking Diagram (5V41236NLG)



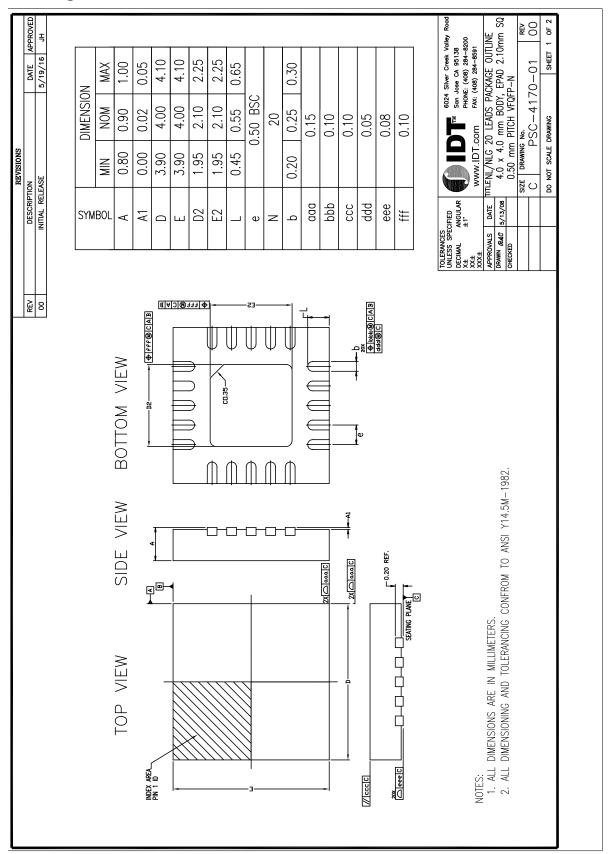
Marking Diagram (5V41236NLGI)



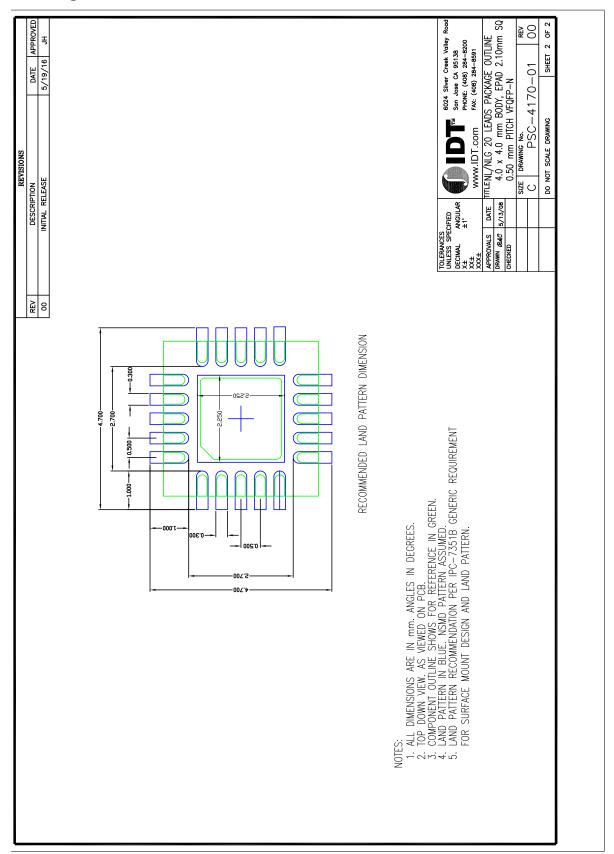
Notes:

- 1."**" denotes lot sequence; "YYWW" or "YWW" Date code; "\$" mark code.
- 2. "G" after the two-letter package code designates RoHS compliant package.
- 3. "I" at the end of part number indicates industrial temperature range.
- 4. Bottom marking: country of origin if not USA. (PGG/I only)

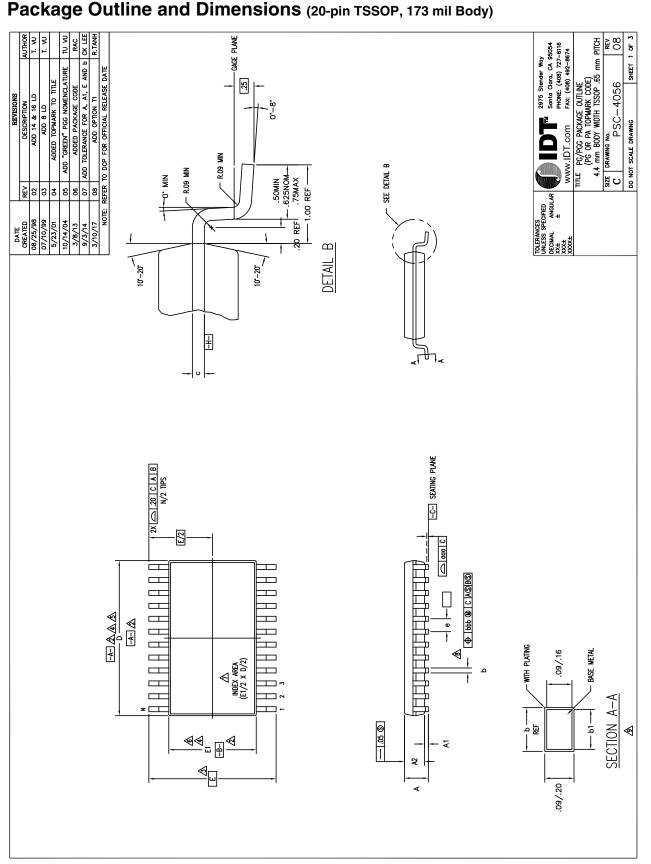
Package Outline and Dimensions (4 × 4 mm, 0.50 Pitch 20-VFQFPN),



Package Outline and Dimensions, cont. (4 × 4 mm, 0.50 Pitch 20-VFQFPN),



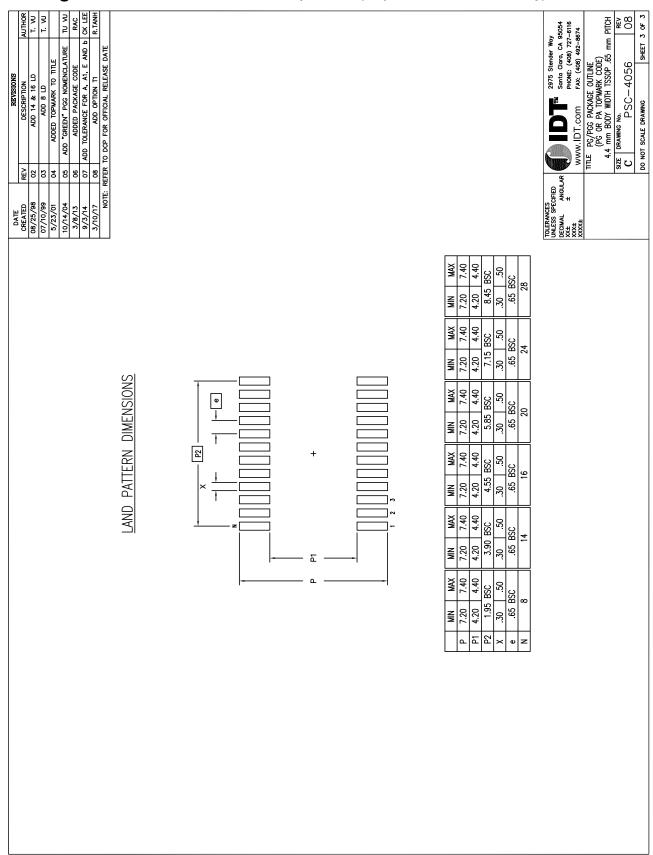
Package Outline and Dimensions (20-pin TSSOP, 173 mil Body)



Package Outline and Dimensions, cont. (20-pin TSSOP, 173 mil Body)

DATE REV DESCRIPTIONS AUTHOR OB/25/98 02 ADD 14 & 16 LD T. VU O7/10/99 03 ADDED TOPMARK TO THE 10/14/04 06 ADDE TOPMARK TO THE 10/14/04 06 ADD "ORED" PGG NOMENCLATURE TU VU 3/24/13 06 ADD "ORED" PGG NOMENCLATURE TU VU 3/24/13 06 ADD TOFFANGE CODE RAC 9/3/14 07 ADD TOLERANGE FOR A, A, I, E AND b CK LEE 3/10/17 08 ADD OPTION TI R.TANH NOTE: REFER TO DOP FOR OFFICIAL RELEASE DATE	PG/PGG24 PG/PGG28	JEDEC VARIATION N JEDEC VARIATION	AD P	MIN NOM MAX L MIN NOM MAX	01. 00. 01.	.80 1.00 1.05 .80 1.00 1.05	6.40 6.60 3 6.20 6.40	4.50 4,6 4.30	.19 .25 .30 .19 .25 .30	.22 .25 .19 .22	01 10	24 28	-	PGC14T1		□ ⊢ ₩	1.20	\vdash	1.00 5.10 4,5 6.60 3	4.50 4	.30	.10 TOLERANCES UNLESS SPECIFIED ECMAL ANGULAR TOLEMANCES SPECIFIED SOTIO CONTROL CAN 30504 TOLEMAN 277-5116 TOLEMAN 277-511	MWW.IDT.com TITE PG/PGG PACKAGE	4 mm BODY WIDTH TSSOP .65 mm F	C PSC-4056 08 non scale drawnic sheet 2 of 3
	PG/PGG20	JEDEC VARIATION	JAC .	MIN NOM MAX 85 110 120	10.	.80 1.00 1.05	6.40 6.60	4.50	.65 BSC .19 25 30	.22	1 1	02			JEDEC	AB-1		59: 8	D 4.90 5.00 F 6.20	6.30	b .19 .25				
	PG/PGG16	JEDEC VARIATION	AB	MIN NOM MAX -	01.	.80 1.00 1.05	6.40	4.30 4.40 4.50 4,6	.65 BSC .19 .25 .30	.22	1 10	16		I-1994		-H-		H 3	H, PROTRUSIONS OR GATE BURRS. SHALL NOT EXCEED .15 mm PER SIDE	JSIONS. INTERLEAD	NITHIN (i, allowable H dimension On the lower	BETWEEN		N MO-153,
	PG/PGG14	JEDEC VARIATION N	AB-1	MIN NOM MAX 5	10	1.00 1.05	6.40	4.30 4.40 4.50 4,6	.65 BSC .19 .25 .30	.22	1 1	14	-	CING CONFORM TO ASME Y14.5N	אים אוידאם דא מקוווויומידדים רם	IO BE DEIERMINED AI DAIUM PLANE) at seating plane [-c-]	BE DETERMINED AT DATUM PLAN		DE INTERLEAD FLASH OR PROTRUSIONS. INTERLEAD NOT EXCEED .25 mm PER SIDE	optional but must be located within	JT INCLUDE DAMBAR PROTRUSION IN EXCESS OF THE LEAD WIDT I. DAMBAR CANNOT BE LOCATED	IE FLAT SECTION OF THE LEAD F 4D TIP	IERS	DEC PUBLICATION 95 REGISTRATION MO-153, 8 AE
	PG/PGG8	JEDEC VARIATION N	*	MIN NOM MAX 5	01.	.80 1.00 1.05	6.40	4.30 4.40 4.50 4,6	.19 .25 .30	.22	1 1	0	NOTES:	ALL DIMENSIONING AND TOLERANCING CONFORM TO ASME Y14.5M-1994		DAIUMS [-A-] AND [-B-] 10	DIMENSION E TO BE DETERMINED AT SEATING	DIMENSIONS D AND E1 ARE TO BE DETERMINED AT DATUM PLANE	DIMENSION D DOES NOT INCLUDE MOLD FLAS MOLD FLASH, PROTRUSIONS OR GATE BURRS	DIMENSION E1 DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSIONS SHALL NOT EXCEED	DETAIL OF PIN 1 IDENTIFIER IS OPTIONAL BUTHE ZONE INDICATED	LEAD WIDTH DIMENSION DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION IS, OB mm IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT	THESE DIMENSIONS APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN .10 AND .25 mm FROM THE LEAD TIP	ALL DIMENSIONS ARE IN MILLIMETERS	THIS OUTLINE CONFORMS TO JEDEC PUBLICAT VARIATION AA, AB-1, AB, AC, AD & AE
		ω≻	Σ#□	□	A1	A2	аш	E1	Ф <u>Ф</u>	P1	900	2		-	«		€	4	•	@	\triangleleft	€		10	11

Package Outline and Dimensions, cont. (20-pin TSSOP, 173 mil Body)



Ordering Information

Part / Order Number	Marking	Shipping Packaging	Package	Temperature
5V41236PGG	see page 11	Tubes	20-pin TSSOP	0 to +70°C
5V41236PGG8		Tape and Reel	20-pin TSSOP	0 to +70°C
5V41236PGGI		Tubes	20-pin TSSOP	-40 to +85°C
5V41236PGGI8		Tape and Reel	20-pin TSSOP	-40 to +85°C
5V41236NLG	see page 11	Trays	20-pin VFQFPN	0 to +70°C
5V41236NLG8		Tape and Reel	20-pin VFQFPN	0 to +70°C
5V41236NLGI		Trays	20-pin VFQFPN	-40 to +85°C
5V41236NLGI8		Tape and Reel	20-pin VFQFPN	-40 to +85°C

[&]quot;G" after the two-letter package code are the Pb-Free configuration, RoHS compliant.

While the information presented herein has been checked for both accuracy and reliability, Integrated Device Technology (IDT) assumes no responsibility for either its use or for the infringement of any patents or other rights of third parties, which would result from its use. No other circuits, patents, or licenses are implied. This product is intended for use in normal commercial applications. Any other applications such as those requiring extended temperature range, high reliability, or other extraordinary environmental requirements are not recommended without additional processing by IDT. IDT reserves the right to change any circuitry or specifications without notice. IDT does not authorize or warrant any IDT product for use in life support devices or critical medical instruments.

Revision History

Rev.	Originator	Date	Description of Change
Α	RDW	09/26/11	Initial release.
В	RDW	11/22/11	Changed title to "4 Output PCIe GEN1/2/3 Synthesizer" Updated Differential Phase Jitter table.
С	LPL	02/04/14	Typo in VFQFPN T&R ordering information and VFQFPN device markings.
D	J.C.	06/06/16	Updated "Operating Supply Current" parameters/values and Conditions in DC Electrical Characteristics table. Updated RPUP, VIH and VIL conditions.
E	RDW	02/13/17	 Updated Operating Supply Current [IDD] typical and maximum values. Added typical values to AC Electrical Characteristics CLKOUT (A:D) table. Updated typical values in Differential Phase Jitter table. Updated 20-VFQFPN POD drawing.
F	RDW	04/04/17	 Update "AC Electrical Characteristics - CLKOUT(A:D)" table values to latest PCIe specifications and characterization data. Updated package outline drawings. Updated legal disclaimer.

Innovate with IDT and accelerate your future networks. Contact:

www.IDT.com

For Sales

800-345-7015 or 408-284-8200

Fax: 408-284-2775 www.idt.com/go/sales For Tech Support

www.idt.com/go/support

Corporate Headquarters

Integrated Device Technology, Inc.

www.idt.com



DISCLAIMER Integrated Device Technology, Inc. (IDT) and its affiliated companies (herein referred to as "IDT") reserve the right to modify the products and/or specifications described herein at any time, without notice, at IDT's sole discretion. Performance specifications and operating parameters of the described products are determined in an independent state and are not guaranteed to perform the same way when installed in customer products. The information contained herein is provided without representation or warranty of any kind, whether express or implied, including, but not limited to, the suitability of IDT's products for any particular purpose, an implied warranty of merchantability, or non-infringement of the intellectual property rights of others. This document is presented only as a guide and does not convey any license under intellectual property rights of IDT or any third parties.

IDT's products are not intended for use in applications involving extreme environmental conditions or in life support systems or similar devices where the failure or malfunction of an IDT product can be reasonably expected to significantly affect the health or safety of users. Anyone using an IDT product in such a manner does so at their own risk, absent an express, written agreement by IDT.

Integrated Device Technology, IDT and the IDT logo are trademarks or registered trademarks of IDT and its subsidiaries in the United States and other countries. Other trademarks used herein are the property of IDT or their respective third party owners. For datasheet type definitions and a glossary of common terms, visit www.idt.com/go/glossary. Integrated Device Technology, Inc.. All rights reserved.

18